

New Jersey Semi-Conductor Products, Inc.

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BYW 78-50 → 200

HIGH EFFICIENCY FAST RECOVERY RECTIFIER DIODES

DESCRIPTION

Low voltage drop rectifiers suited for switching mode power supply.

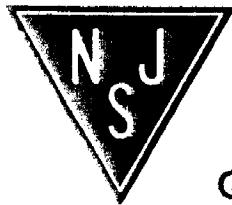
ABSOLUTE MAXIMUM RATINGS (limiting values)

Symbol	Parameter	Value	Unit
I _{FRM}	Repetitive Peak Forward Current $t_p \leq 20\mu s$	1000	A
I _F (RMS)	RMS Forward Current	100	A
I _F (AV)	Average Forward Current $T_c = 100^\circ C$ $\delta = 0.5$	50	A
I _{FSM}	Surge non Repetitive Forward Current $t_p = 10ms$ Sinusoidal	1500	A
P _{tot}	Power Dissipation $T = 90^\circ C$	60	W
T _{sig} T _J	Storage and Junction Temperature Range	-40 to +150 -40 to +150	°C

Symbol	Parameter	BYT 78-				Unit
		50	100	150	200	
V _{RRM}	Repetitive Peak Reverse Voltage	50	100	150	200	V
V _{RSM}	Non Repetitive Peak Reverse Voltage	55	110	165	220	V

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th} (J - c)	Junction-case	1	°C/W



Quality Semi-Conductors

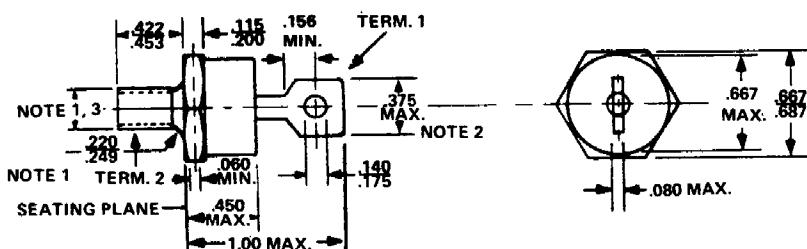
ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
I_R	$T_J = 25^\circ C$	$V_R = V_{RRM}$			50	μA
	$T_J = 100^\circ C$				5	mA
V_F	$T_J = 25^\circ C$	$I_F = 160A$			1.1	V
	$T_J = 100^\circ C$	$I_F = 50A$			0.85	

RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
t_{rr}	$T_J = 25^\circ C$ $V_R = 30V$	$I_F = 1A$ see figure 12	$dI_F/dt = -50A/\mu s$			60	ns
t_r	$T_J = 25^\circ C$ Measured at $1.1 \times V_F$	$I_F = 1A$	$t_r = 5ns$		10		ns
V_{FP}	$T_J = 25^\circ C$	$I_F = 1A$	$t_r = 5ns$		1.5		V



NOTES:

1. COMPLETE THREADS TO EXTEND TO WITHIN 2-1/2 THREADS OF SEATING PLANE.
2. ANGULAR ORIENTATION OF THIS TERMINAL IS UNDEFINED.
3. 1/4-28 UNF-2A. MAXIMUM PITCH DIAMETER OF PLATED THREADS SHALL BE BASIC PITCH DIAMETER (.2268", 5.74 MM) REF. (SCREW THREAD STANDARDS FOR FEDERAL SERVICES 1957) HANDBOOK H28 1957 P1.
4. MINIMUM FLAT.